# NSN 5962-01-191-3471

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# **Body Length:**

1.290 inches

## Body Width:

Between 0.500 inches and 0.610 inches

## **Body Height:**

0.210 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and burn in and programmable and 3-state output

## **Inclosure Material:**

Ceramic

## Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Metal oxide-semiconductor logic

## Input Circuit Pattern:

14 input

Case Outline Source And Designator:

D-3 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output

### Memory Device Type:

Rom

### Memory Capacity:

Unknown

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

### **Terminal Type And Quantity:**

24 printed circuit

## Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

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